

# DESCRIPTION

The AO324V have a high gain-bandwidth product of 1MHz, a slew rate of 0.6V/µs, and a quiescent current of 40µA/amplifier at 5V. The AO324V is designed to provide optimal performance in low voltage and low noise systems. They provide rail-to-rail output swing into heavy loads. The input common mode voltage range includes ground, and the maximum input offset voltage is 3.5mV for AO324V. They are specified over the extended industrial temperature range (-40°C to +125°C). The operating range is from 2.1V to 5.5V.

The AO324V (quad) is available in SOP14 package.

### **ORDERING INFORMATION**

Package Type	Part Number				
SOP14	M14	AO324VM14R			
SPQ: 2,500pcs/Reel	IVI 14	AO324VM14VR			
Nata	V: Haloger	n free Package			
Note	R: Tape &	Reel			
AiT provides all RoHS products					

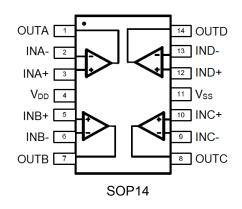
## FEATURES

- Single-Supply Operation from +2.1V ~ +5.5V
- Rail-to-Rail Input / Output
- Gain-Bandwidth Product: 1MHz (Typ.)
- Low Input Bias Current: 1pA (Typ.)
- Low Offset Voltage: 3.5mV (Max.)
- Quiescent Current: 40µA per Amplifier (Typ.)
- Operating Temperature: -40°C ~ +125°C
- Embedded RF Anti-EMI Filter
- Available in SOP14 package

### APPLICATION

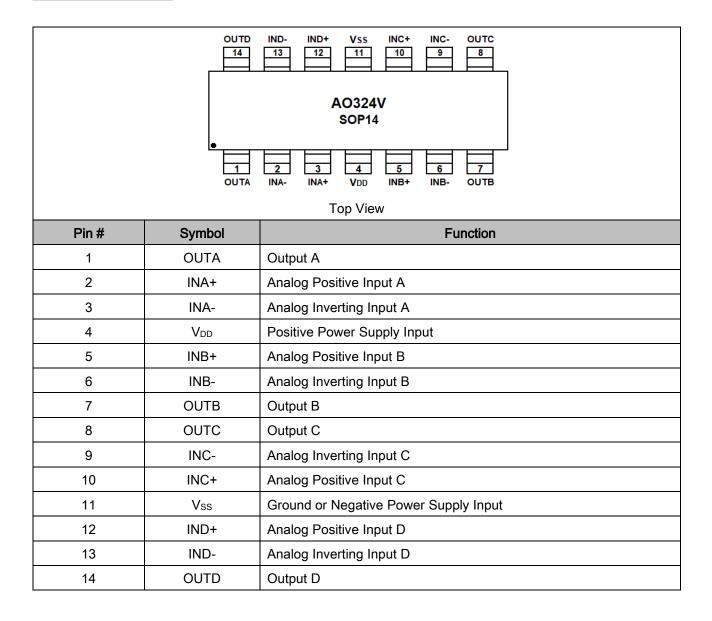
- ASIC Input or Output Amplifier
- Sensor Interface
- Medical Communication
- Smoke Detectors
- Audio Output
- Piezoelectric Transducer Amplifier
- Medical Instrumentation
- Portable Systems

### **TYPICAL APPLICATION**





# PIN DESCRIPTION





# ABSOLUTE MAXIMUM RATINGS

Power Supply Voltage (VDD to VSS)	-0.5V~+7.5V
Analog Input Voltage (IN+ or IN-)	V <sub>SS</sub> -0.5V~V <sub>DD</sub> +0.5V
PDB Input Voltage	V <sub>SS</sub> -0.5V~+7V
Operating Temperature Range	-40°C~+125°C
Junction Temperature	+160°C
Storage Temperature Range	-55°C~+150°C
Lead Temperature (soldering, 10sec)	+260°C
ESD Susceptibility	
НВМ	6kV
ММ	300∨

Stress beyond above listed "Absolute Maximum Ratings" may lead permanent damage to the device. These are stress ratings only and operations of the device at these or any other conditions beyond those indicated in the operational sections of the specifications are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



# ELECTRICAL CHARACTERISTICS

			Тур	Min/Max Over Temperature			
Parameter	Symbol	Conditions	+25℃	+25℃	-40℃ to +85℃	Unit	Min / Max
INPUT CHARACTERISTICS							
Input Offset Voltage	Vos	V <sub>CM</sub> = V <sub>S</sub> /2	0.4	3.5	5.6	mV	Max
Input Bias Current	lв		1	-	-	pА	Тур
Input Offset Current	los		1	-	-	pА	Тур
Common-Mode Voltage Range	Vсм	V <sub>S</sub> = 5.5V	-0.1 to +5.6	-	-	V	Тур
Common-Mode Rejection Ratio	CMRR	V <sub>S</sub> = 5.5V, V <sub>CM</sub> = -0.1V to 4V	70	62	62	dB	Min
		Vs = 5.5V, V <sub>CM</sub> = -0.1V to 5.6V	68	56	55		
Open-Loop Voltage Gain		$R_L = 5k\Omega$ , V <sub>0</sub> = +0.1V to +4.9V	80	70	70	dB	Min
	Aol	$R_L = 10k\Omega$ , V <sub>O</sub> = +0.1V to +4.9V	100	94	85		
Input Offset Voltage Drift	ΔV <sub>OS</sub> /Δ <sub>T</sub>		2.7	-	-	µV/°C	Тур
OUTPUT CHARACTERISTICS							
	V <sub>OH</sub>	R <sub>L</sub> = 100kΩ	4.997	4.990	4.980	V	Min
	V <sub>OL</sub>	R <sub>L</sub> = 100kΩ	3	10	20	mV	Max
Output Voltage Swing from Rail	V <sub>OH</sub>	R <sub>L</sub> = 10kΩ	4.992	4.970	4.960	V	Min
	V <sub>OL</sub>	R <sub>L</sub> = 10kΩ	8	30	40	mV	Max
	ISOURCE	$R_L$ = 10 $\Omega$ to V <sub>S</sub> /2	84	60	45	mA	Min
Output Current	I <sub>SINK</sub>		75	60	45		
POWER SUPPLY			_				
Operating Voltage Range			-	2.1	2.5	V	Min
			-	5.5	5.5	V	Max
Power Supply Rejection Ratio	PSRR	$V_{S}$ = +2.5V to +5.5V, $V_{CM}$ = +0.5V	82	60	58	dB	Min
Quiescent Current/Amplifier	lq		40	-	-	μA	Тур

At V<sub>S</sub> = +5V, R<sub>L</sub> = 100k $\Omega$  connected to V<sub>S</sub>/2, and V<sub>OUT</sub> = V<sub>S</sub>/2, unless otherwise noted.

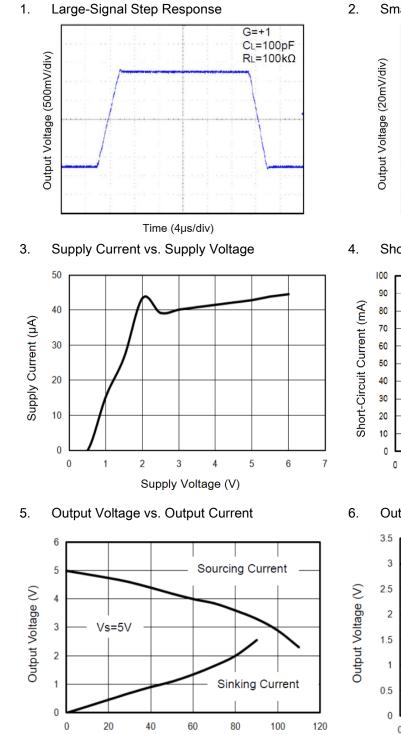


			Тур	Min/Max Over Temperature				
Parameter Symbol	Symbol	Conditions	+25℃	+25℃	-40℃ to +85℃	Unit	Min / Max	
DYNAMIC PERFORMANCE (CL = 100pF)								
Gain-Bandwidth Product	GBP		1	-	-	MHz	Тур	
Slew Rate	SR	G = +1, 2V Output Step	0.6	-	-	V/µs	Тур	
Settling Time to 0.1%	ts	G = +1, 2V Output Step	5	-	-	μs	Тур	
Overload Recovery Time		V <sub>IN</sub> ⋅Gain = V <sub>S</sub>	2.6	-	-	μs	Тур	
NOISE PERFORMANCE								
Voltage Noise Density	en	f = 1kHz	27	-	-	nV/ √Hz	Тур	
		f = 10kHz	20	-	-	nV/ √Hz	Тур	

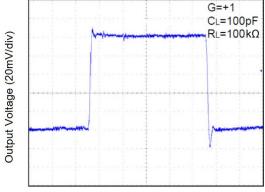


# TYPICAL PERFORMANCE CHARACTERISTICS

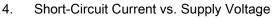
At T<sub>A</sub>=+25°C, V<sub>S</sub>=+5V, and R<sub>L</sub>=100k $\Omega$  connected to V<sub>S</sub>/2, unless otherwise noted.

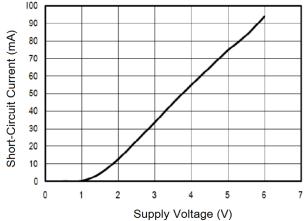


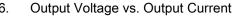
Small-Signal Step Response

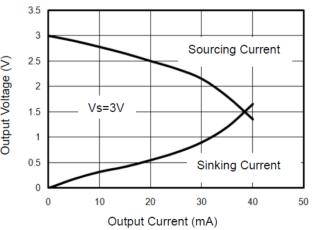








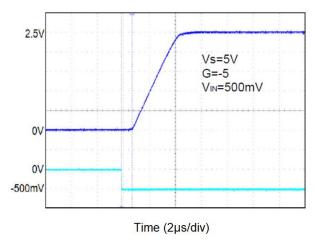




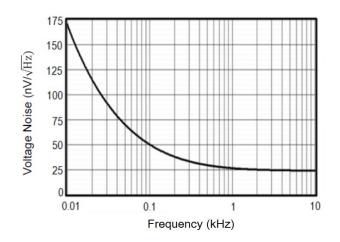
Output Current (mA)

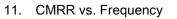


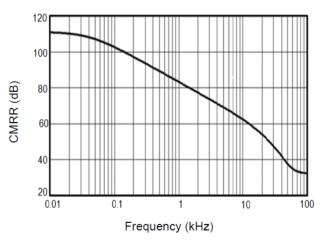
#### 7. Overload Recovery Time



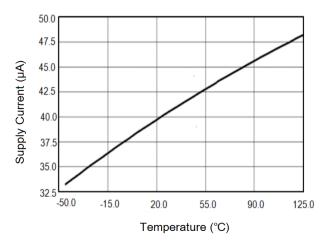
9. Input Voltage Noise Spectral Density vs. Frequency



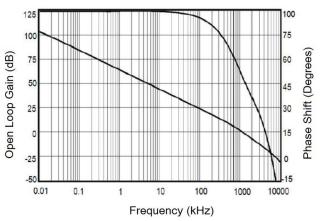




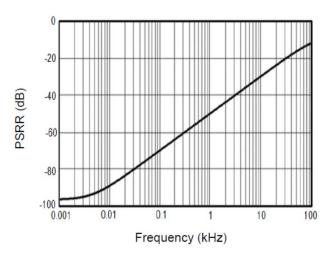
8. Supply Current vs. Temperature



 Open Loop Gain, Phase Shift vs. Frequency at +5V



12. PSRR vs. Frequency





## DETAILED INFORMATION

#### Size

AO324V op amps are unity-gain stable and suitable for a wide range of general-purpose applications. The small footprints of the AO324V packages save space on printed circuit boards and enable the design of smaller electronic products.

#### Power Supply Bypassing and Board Layout

AO324V operates from a single 2.1V to 5.5V supply or dual  $\pm 1.05V$  to  $\pm 2.75V$  supplies. For best performance, a 0.1µF ceramic capacitor should be placed close to the V<sub>DD</sub> pin in single supply operation. For dual supply operation, both V<sub>DD</sub> and V<sub>SS</sub> supplies should be bypassed to ground with separate 0.1µF ceramic capacitors.

#### Low Supply Current

The low supply current (typical 40uA per channel) of AO324V will help to maximize battery life. They are ideal for battery powered systems

#### **Operating Voltage**

AO324V operates under wide input supply voltage (2.1V to 5.5V). In addition, all temperature specifications apply from -40°C to +125°C. Most behavior remains unchanged throughout the full operating voltage range. These guarantees ensure operation throughout the single Li-Ion battery lifetime

#### Rail-to-Rail Input

The input common-mode range of AO324V extends 100mV beyond the supply rails ( $V_{SS}$ -0.1V to  $V_{DD}$ +0.1V). This is achieved by using complementary input stage. For normal operation, inputs should be limited to this range.

#### Rail-to-Rail Output

Rail-to-Rail output swing provides maximum possible dynamic range at the output. This is particularly important when operating in low supply voltages. The output voltage of AO324V can typically swing to less than 5mV from supply rail in light resistive loads (>100k $\Omega$ ), and 30mV of supply rail in moderate resistive loads (10k $\Omega$ ).



#### **Capacitive Load Tolerance**

The AO324V is optimized for bandwidth and speed, not for driving capacitive loads. Output capacitance will create a pole in the amplifier's feedback path, leading to excessive peaking and potential oscillation. If dealing with load capacitance is a requirement of the application, the two strategies to consider are (1) using a small resistor in series with the amplifier's output and the load capacitance and (2) reducing the bandwidth of the amplifier's feedback loop by increasing the overall noise gain. Figure 1. shows a unity gain follower using the series resistor strategy. The resistor isolates the output from the capacitance and, more importantly, creates a zero in the feedback path that compensates for the pole created by the output capacitance.

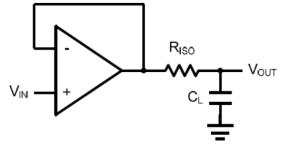


Figure 1. Indirectly Driving a Capacitive Load Using Isolation Resistor

The bigger the  $R_{ISO}$  resistor value, the more stable  $V_{OUT}$  will be. However, if there is a resistive load  $R_L$  in parallel with the capacitive load, a voltage divider (proportional to  $R_{ISO}/R_L$ ) is formed, this will result in a gain error.

The circuit in Figure 2 is an improvement to the one in Figure 1.  $R_F$  provides the DC accuracy by feed-forward the V<sub>IN</sub> to R<sub>L</sub>. C<sub>F</sub> and R<sub>ISO</sub> serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving the phase margin in the overall feedback loop. Capacitive drive can be increased by increasing the value of C<sub>F</sub>. This in turn will slow down the pulse response.

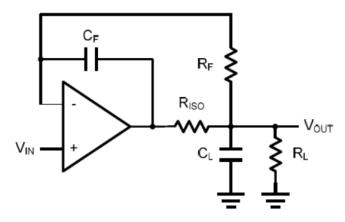


Figure 2. Indirectly Driving a Capacitive Load with DC Accuracy



### **Typical Application Circuits**

#### Differential amplifier

The differential amplifier allows the subtraction of two input voltages or cancellation of a signal common the two inputs. It is useful as a computational amplifier in making a differential to single-end conversion or in rejecting a common mode signal. Figure 3. shown the differential amplifier using AO324V.

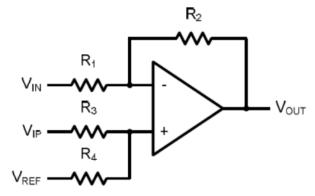


Figure 3. Differential Amplifier

 $V_{OUT} = \left(\frac{R_1 + R_2}{R_3 + R_4}\right) \frac{R_4}{R_1} V_{IN} - \frac{R_2}{R_1} V_{IP} + \left(\frac{R_1 + R_2}{R_3 + R_4}\right) \frac{R_3}{R_1} V_{REF}$ 

If the resistor ratios are equal (i.e.  $R_1=R_3$  and  $R_2=R_4$ ), then

$$V_{OUT} = \frac{R_2}{R_1} (V_{IP} - V_{IN}) + V_{REF}$$

#### Low Pass Active Filter

The low pass active filter is shown in Figure 4. The DC gain is defined by  $-R_2/R_1$ . The filter has a -20dB/decade roll-off after its corner frequency  $f_c=1/(2\pi R_3C_1)$ .

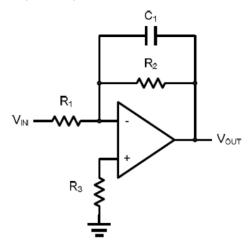


Figure 4. Low Pass Active Filter



#### Instrumentation Amplifier

The triple AO324V can be used to build a three-op-amp instrumentation amplifier as shown in Figure 5. The amplifier in Figure 5 is a high input impedance differential amplifier with gain of  $R_2/R_1$ . The two differential voltage followers assure the high input impedance of the amplifier.

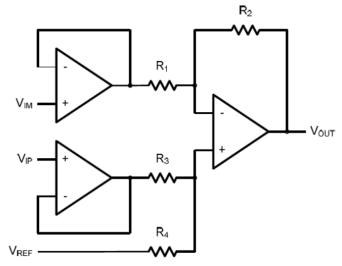
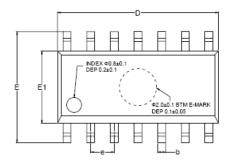


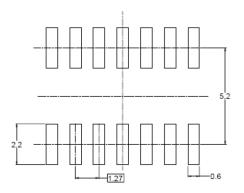
Figure 5. Instrument Amplifier



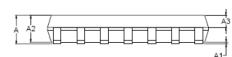
# PACKAGE INFORMATION

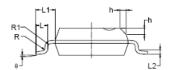
Dimension in SOP14 (Unit: mm)





RECOMMENDED LAND PATTERN (Unit: mm)





O: maked	Millim	neters	Inches			
Symbol	Min.	Max.	Min.	Max.		
А	1.35	1.75	0.053	0.069		
A1	0.10	0.25	0.004	0.010		
A2	1.25	1.65	0.049	0.065		
A3	0.55	0.75	0.022	0.030		
b	0.36	0.49	0.014	0.019		
D	8.53	8.73	0.336	0.344		
E	5.80	6.20	0.228	0.244		
E1	3.80	4.00	0.150	0.157		
е	1.27	BSC	0.050	0.050 BSC		
L	0.45	0.80	0.018	0.032		
L1	1.04 REF		0.040 REF			
L2	0.25	BSC	0.010 BSC			
R	0.07	-	0.003	-		
R1	0.07	-	0.003	-		
h	0.30	0.50	0.012	0.020		
θ	0°	8°	0°	8°		



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